## NSN 5961-01-373-7793

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Inclosure Material:
Metal
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
12.0 reverse voltage, instantaneous and 14.1 breakdown voltage, instantaneous
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0